NSN 5962-01-143-6833

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-143-6833

view Offilite at https://defobasegroup.com/hsr//0902-01-140-0000
Body Length:
Between 1.235 inches and 1.285 inches
Body Width:
Between 0.515 inches and 0.600 inches
Body Height:
Between 0.145 inches and 0.175 inches
Maximum Power Dissipation Rating:
525.0 milliwatts
Operating Tempurature Range:
-10.0/+80.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
End Application:
Bit verificat 82577
Features Provided:
Erasable and programmable and static operation and high speed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
11 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.0 volts power source
Time Rating Per Chacteristic:
650.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
82577-1090135 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

NSN 5962-01-143-6833

Memory Microcircuit - Page 2 of 2



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